



PJU60N08 / PJD60N08 / PJP60N08

Current

60 A

80V N-Channel Enhancement Mode MOSFET

Voltage

lage

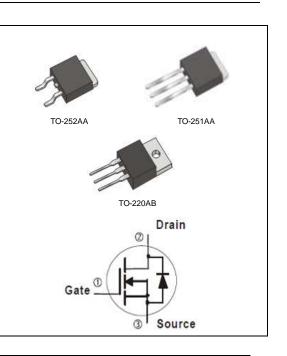
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A < 10m\Omega$
- High switching speed
- Low Gate Charge
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

80 V

Mechanical Data

- Case : TO-251AA,TO-252AA ,TO-220AB Package
- Terminals : Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	TO-252AA	UNITS
Drain-Source Voltage		V _{DS}	80			V
Gate-Source Voltage		V _{GS}	<u>+</u> 25			V
Continuous Drain Current	T _C =25°C	I _D	60			A
	T _c =100°C		38			
Pulsed Drain Current	T _C =25°C	I _{DM}	180			
Power Dissipation	T _C =25°C	PD	76	100	76	w
	T _c =100°C		30	40	30	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	180			mJ
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150			°C
Typical Thermal Resistance						
- Junction to Case		$R_{ extsf{ heta}JC}$	1.64	1.25	1.64	°C/W
- Junction to Ambient		$R_{ heta JA}$	110	62.5	110	

Limited only By Maximum Junction Temperature





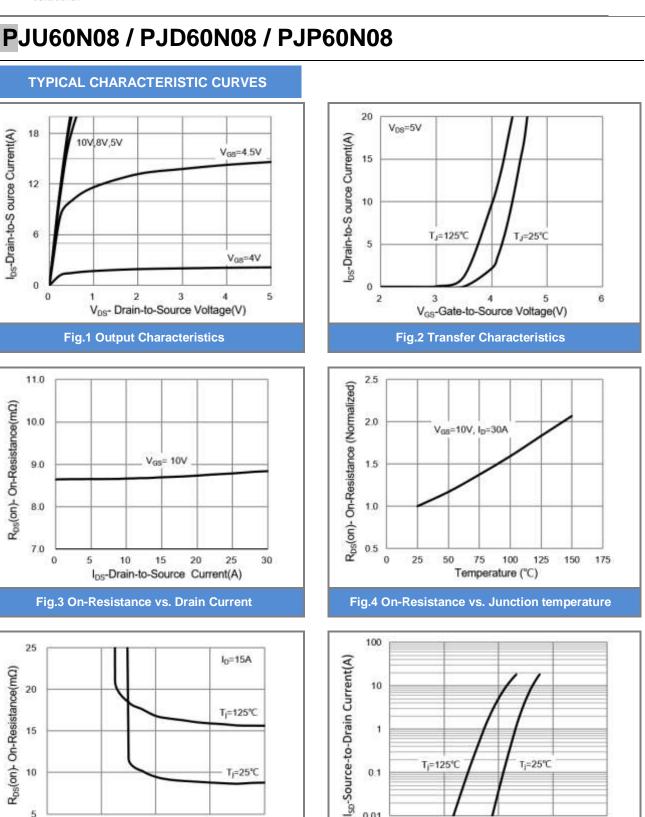
Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	80	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2.0	3.0	4.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =20A	-	8.8	10	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =64V,V _{GS} =0V	-	-	1.0	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 25V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	Qg		-	73	-	nC	
Gate-Source Charge	Q _{gs}	V _{DS} =30V, I _D =30A, V _{GS} =10V ^(Note 1,2)	-	17	-		
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	20	-		
Input Capacitance	Ciss		-	3855	-	pF	
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	- UV,	292	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	172	-		
Turn-On Delay Time	td _(on)		-	19	-		
Turn-On Rise Time	tr	V_{DD} =30V, I_{D} =30A,	-	79	-		
Turn-Off Delay Time	td _(off)	$V_{GS}=10V, R_G=6\Omega$		71	-	ns	
Turn-Off Fall Time	t _f		-	54	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	60	А	
Diode Forward Current	I _S						
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.8	1.0	V	

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. Roua is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, $I_{\text{AS}}{=}60\text{A},\,V_{\text{DD}}{=}25\text{V},\,V_{\text{GS}}{=}10\text{V}$
- 7. Guaranteed by design, not subject to production testing.





Tj=25℃

10

8

6

V_{GS}-Gate-to-Source Voltage(V)

Fig.5 On-Resistance Variation with VGS.

10

5

2

1.2

Tj=25℃

0.3 0.6 0.9 V_{SD}-Source-to-Drain Voltage(V)

Fig.6 Source-Drain Diode Forward Voltage

Tj=125°C

0.1

0.01

0



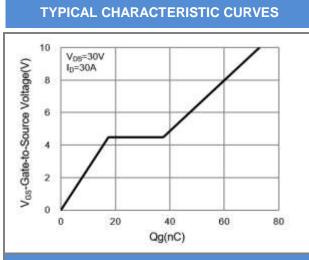


Fig.7 Gate-Charge Characteristics

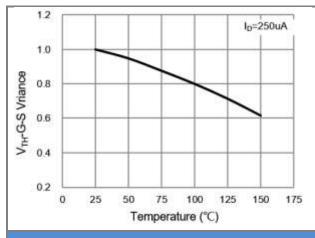
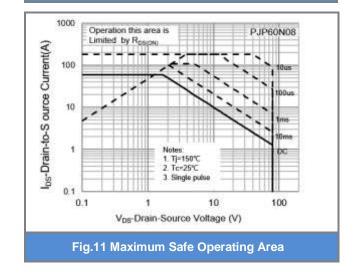


Fig.9 Threshold Voltage Variation with Temperature



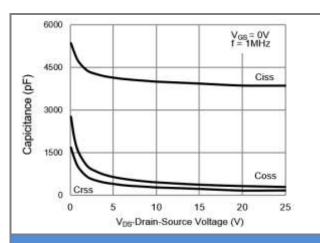


Fig.8 Capacitance vs. Drain-Source Voltage

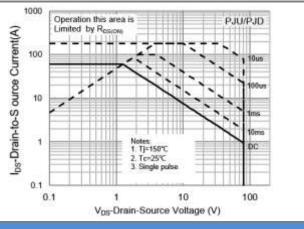
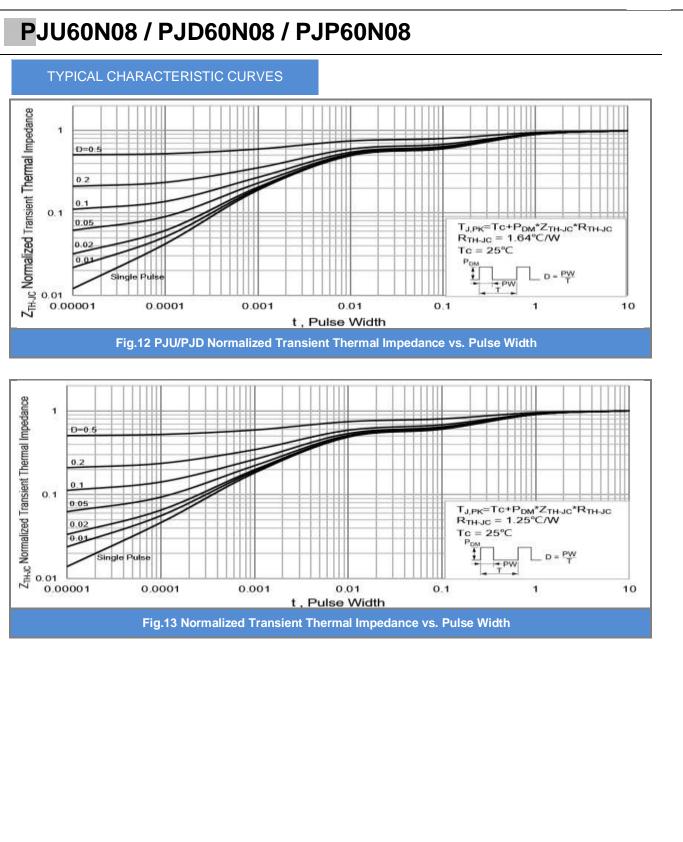


Fig.10 Maximum Safe Operating Area

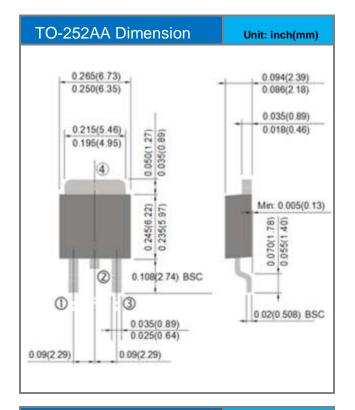


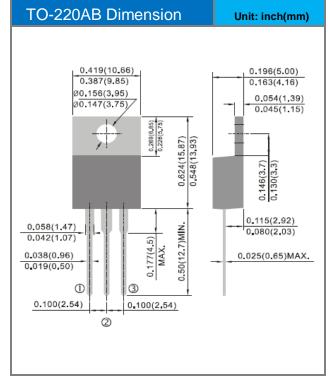


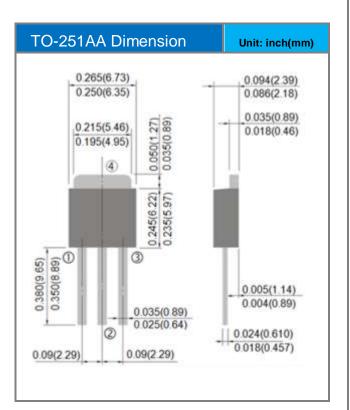




Packaging Information











PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU60N08_T0_00001	TO-251AA	80pcs / Tube	U60N08	Halogen free
PJD60N08_L2_00001	TO-252AA	3,000pcs / 13" reel	D60N08	Halogen free
PJP60N08_T0_00001	TO-220AB	50pcs / Tube	P60N08	Halogen free





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